

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (Ultra-High-Speed U-MOSIII)

# TPC6109-H

## High-Efficiency DC-DC Converter Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance:  $R_{DS(ON)} = 44 \text{ m}\Omega$  (typ.)  
( $V_{DS} = -10 \text{ V}$ )
- High forward transfer admittance:  $|Y_{fs}| = 8.0 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = -10 \text{ }\mu\text{A}$  (max) ( $V_{DS} = -30 \text{ V}$ )
- Enhancement mode:  $V_{th} = -0.8 \text{ to } -2.0 \text{ V}$  ( $V_{DS} = -10 \text{ V}$ ,  $I_D = -1 \text{ mA}$ )

## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	-30	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )	$V_{DGR}$	-30	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	V
Drain current	DC (Note 1)	$I_D$	-5
	Pulse (Note 1)	$I_{DP}$	-20
Drain power dissipation ( $t = 5 \text{ s}$ ) (Note 2a)	$P_D$	2.2	W
Single-pulse avalanche energy (Note 3)	$E_{AS}$	16.3	mJ
Avalanche current	$I_{AR}$	-5	A
Repetitive avalanche energy (Note 4)	$E_{AR}$	0.055	mJ
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

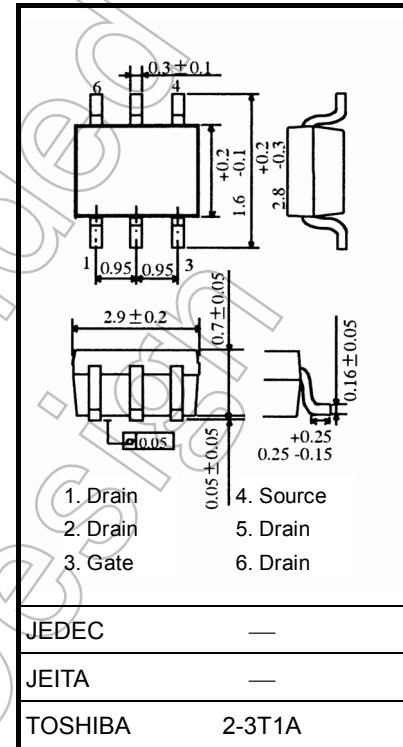
## Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient ( $t = 5 \text{ s}$ ) (Note 2a)	$R_{th(ch-a)}$	56.8	$^\circ\text{C/W}$
Thermal resistance, channel to ambient ( $t = 5 \text{ s}$ ) (Note 2b)	$R_{th(ch-a)}$	178.5	$^\circ\text{C/W}$

Note: For Notes 1 to 5, see page 3.

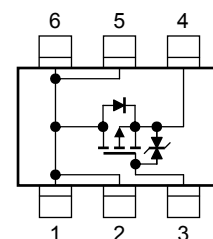
Caution: This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm

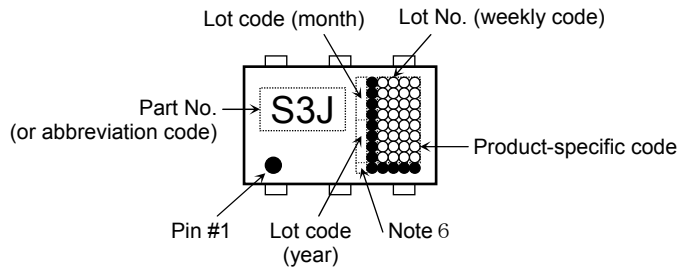


Weight: 0.011 g (typ.)

## Circuit Configuration



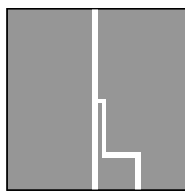
## Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

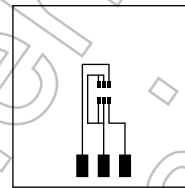
Note 2: (a) Device mounted on a glass-epoxy board (a) ( $t = 5$  s)

(b) Device mounted on a glass-epoxy board (b) ( $t = 5$  s)



(a)

FR-4  
25.4 × 25.4 × 0.8  
(Unit: mm)



(b)

FR-4  
25.4 × 25.4 × 0.8  
(Unit: mm)

Note 3:  $V_{DD} = -24$  V,  $T_{ch} = 25^{\circ}\text{C}$  (initial),  $L = 500$   $\mu\text{H}$ ,  $R_G = 25$   $\Omega$ ,  $I_{AR} = -5$  A

Note 4: Repetitive rating: pulse width limited by max channel temperature

Note 5: ● to the lower left of the Part No. marking indicates Pin 1.

Note 6: A dot marking identifies the indication of product Labels.

Without a dot: [[Pb]]/INCLUDES > MCV

With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

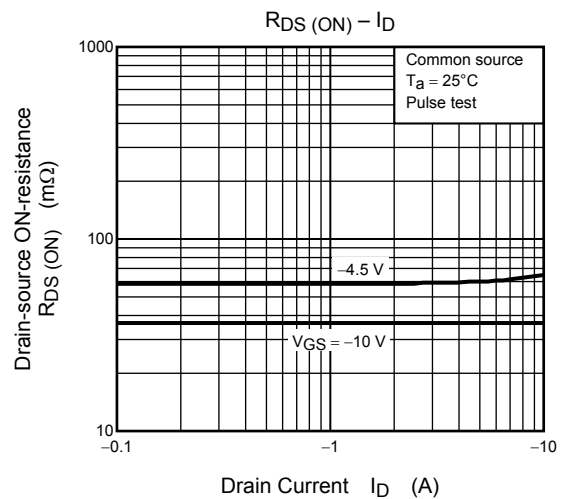
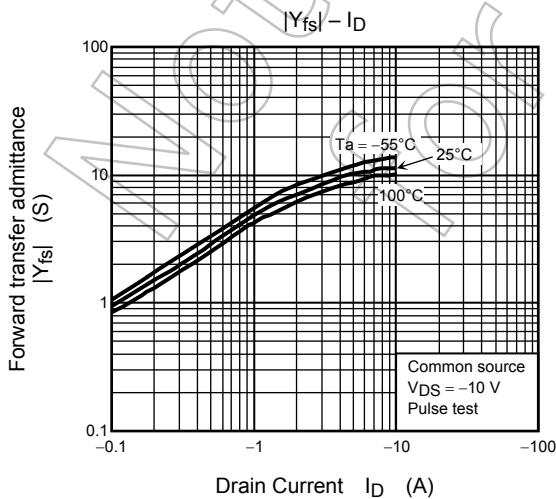
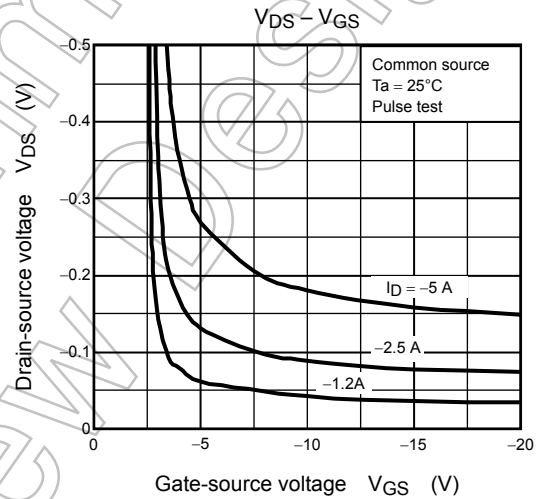
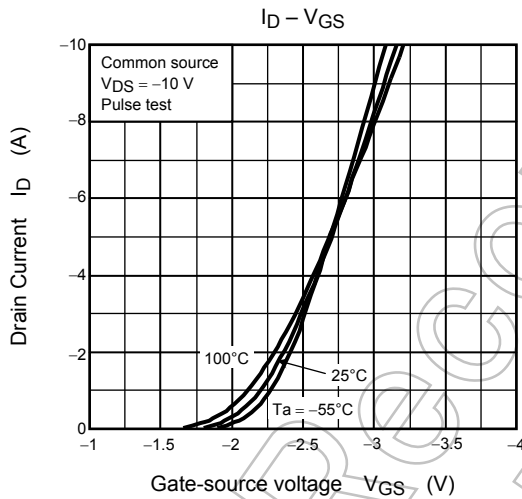
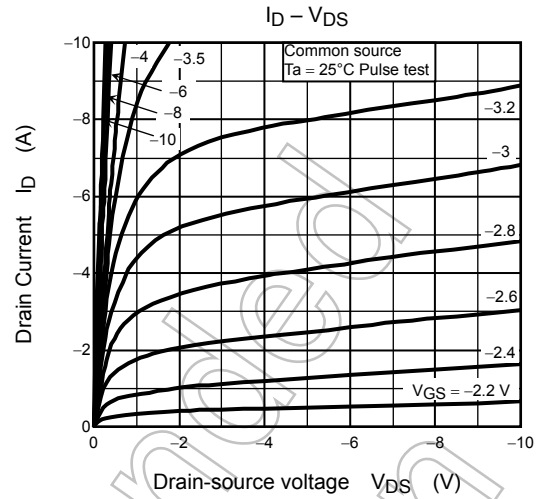
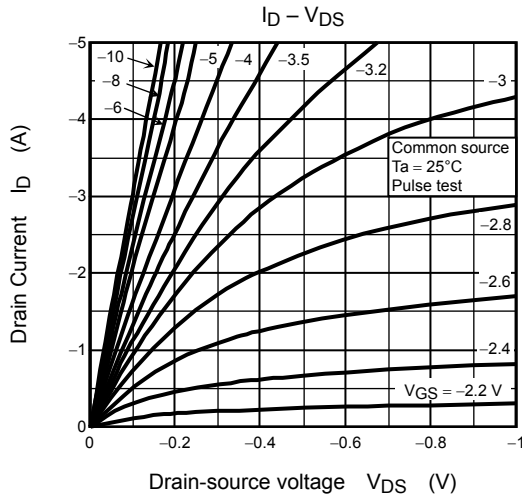
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

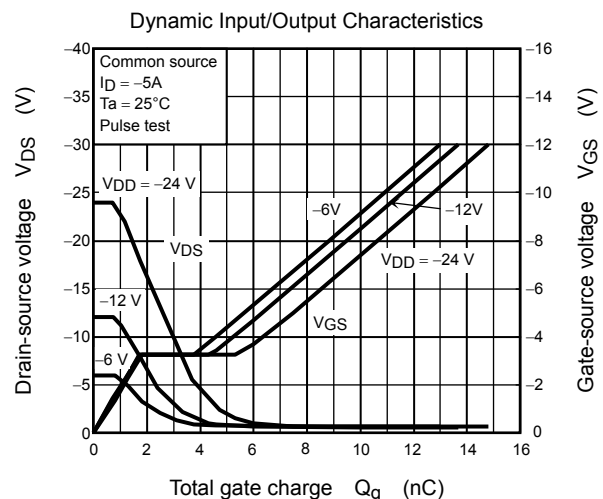
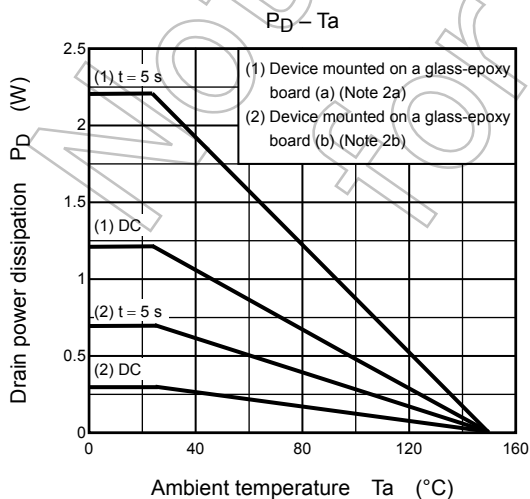
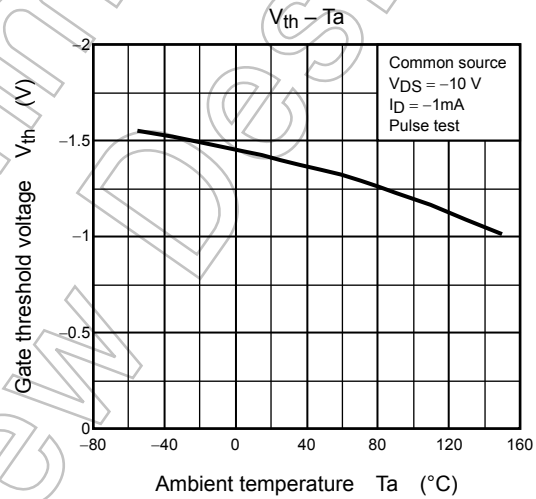
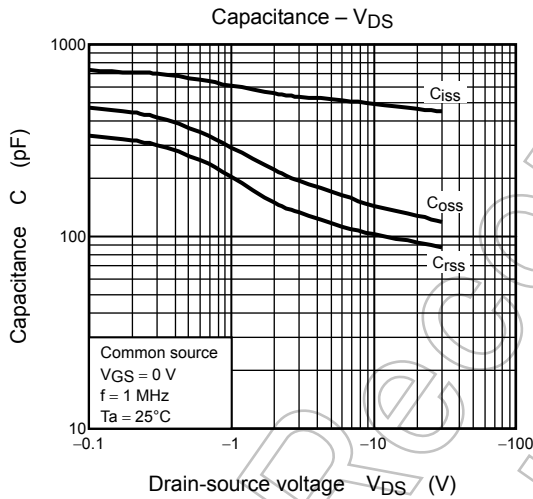
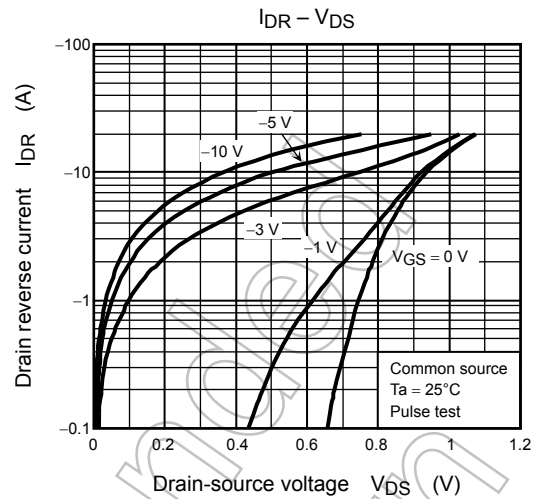
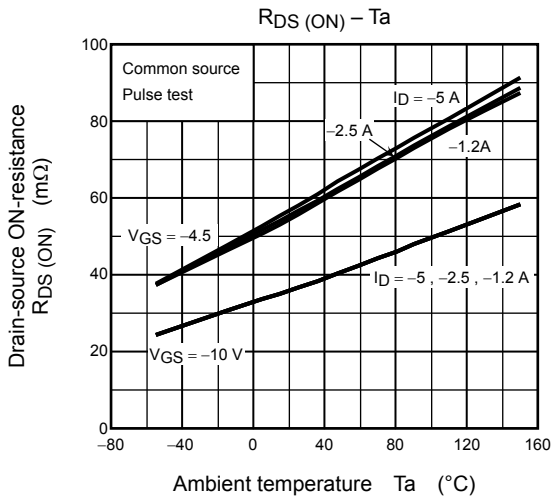
## Electrical Characteristics (Ta = 25°C)

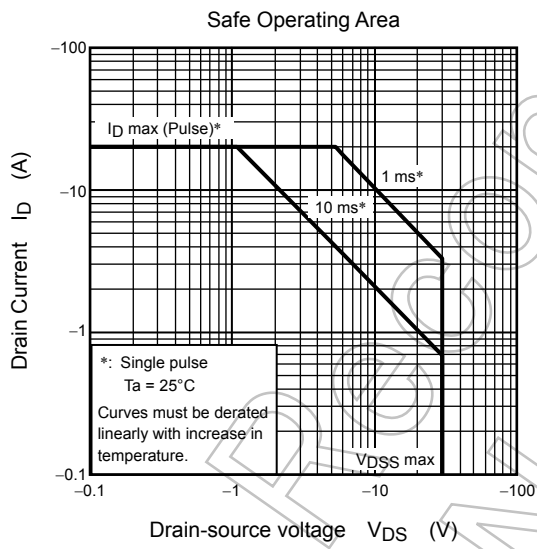
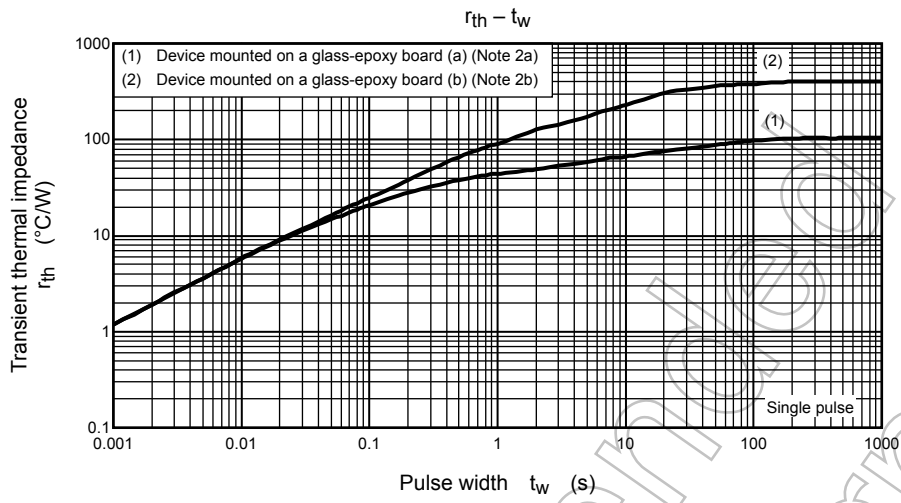
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		$I_{GSS}$	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Drain cut-off current		$I_{DSS}$	$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$	—	—	-10	$\mu\text{A}$
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$	-30	—	—	V
		$V_{(BR)DSX}$	$I_D = -10\text{ mA}, V_{GS} = 20\text{ V}$	-15	—	—	
Gate threshold voltage		$V_{th}$	$V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$	-0.8	—	-2.0	V
Drain-source ON resistance		$R_{DS(ON)}$	$V_{GS} = -4.5\text{ V}, I_D = -2.5\text{ A}$	—	64	83	m $\Omega$
		$R_{DS(ON)}$	$V_{GS} = -10\text{ V}, I_D = -2.5\text{ A}$	—	44	59	
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = -10\text{ V}, I_D = -2.5\text{ A}$	4.0	8.0	—	S
Input capacitance		$C_{iss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	490	—	pF
Reverse transfer capacitance		$C_{rss}$		—	105	—	
Output capacitance		$C_{oss}$		—	150	—	
Switching time	Rise time	$t_r$		—	5.1	—	ns
	Turn-on time	$t_{on}$		—	10.7	—	
	Fall time	$t_f$		—	8.0	—	
	Turn-off time	$t_{off}$		Duty $\leq 1\%$ , $t_w = 10\ \mu\text{s}$	—	33.5	
Total gate charge (gate-source plus gate-drain)		$Q_g$	$V_{DD} \approx -24\text{ V}, V_{GS} = -10\text{ V}, I_D = -5\text{ A}$	—	12.3	—	nC
			$V_{DD} \approx -24\text{ V}, V_{GS} = -5\text{ V}, I_D = -5\text{ A}$	—	7.2	—	
Gate-source charge1		$Q_{gs1}$	$V_{DD} \approx -24\text{ V}, V_{GS} = -10\text{ V}, I_D = -5\text{ A}$	—	1.7	—	
Gate-drain ("Miller") charge		$Q_{gd}$		—	3.6	—	
Gate switch charge		$Q_{sw}$		—	4.8	—	

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	$I_{DRP}$	—	—	—	-20	A
Forward voltage (diode)		$V_{DSF}$	$I_{DR} = -5\text{ A}, V_{GS} = 0\text{ V}$	—	—	1.2	V







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